

**LIST OF PRIOR ART  
CITED BY APPLICANT**

(Use several sheets if necessary)

**Atty. Docket No.**  
YOR920010308US3 (163158)

**Serial N .**  
Unassigned

**Applicant**  
Jack O. Chu, et al.

**Filing Date**  
Herewith

**Group**  
Unassigned

**U.S. PATENT DOCUMENTS**

EXAMINER INITIAL*		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (if appropriate)
	AA	5,906,680	5/25/1999	Meyerson			
	AB	6,190,975	2/2001	Kubo et al			
		2001/0160605	10/2002	Kanazawa et al.;			
		5,683,934	11/1997	Candelaria et al			
		2002/0016085	2/2002	Huang et al			
		6,306,211	10/2001	Takahashi et al.			

**FOREIGN PATENT DOCUMENTS**

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO

**OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)**

	E. Kasper, et al. "Growth of 100 Ghz SiGe-Heterobipolar Transistor (HBT) Structures," Jpn J App Phys, Vol. 33 Pt. 1, No. 4B, April 1994, pp. 2415-2418;
	H.J. Osten et al. " in the paper entitled "Carbon Doped SiGe Heterojunction Bipolar Transistors for High Frequency Application," IEEE BCTM 7.1, 1999, pp. 109-116;

**EXAMINER** J. MONDT

**DATE CONSIDERED** 04/16/06.

\* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.